

## Is Now Part of



## ON Semiconductor®

# To learn more about ON Semiconductor, please visit our website at www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to <a href="mailto:Fairchild\_questions@onsemi.com">Fairchild\_questions@onsemi.com</a>.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees



February 1984 Revised August 2000

# MM74HC4538 Dual Retriggerable Monostable Multivibrator

### **General Description**

The MM74HC4538 high speed monostable multivibrator (one shots) is implemented in advanced silicon-gate CMOS technology. They feature speeds comparable to low power Schottky TTL circuitry while retaining the low power and high noise immunity characteristic of CMOS circuits.

Each multivibrator features both a negative, A, and a positive, B, transition triggered input, either of which can be used as an inhibit input. Also included is a clear input that when taken low resets the one shot. The MM74HC4538 is retriggerable. That is, it may be triggered repeatedly while their outputs are generating a pulse and the pulse will be extended.

Pulse width stability over a wide range of temperature and supply is achieved using linear CMOS techniques. The output pulse equation is simply: PW=0.7(R)(C) where PW is in seconds, R is in ohms, and C is in farads. This device is pin compatible with the CD4528, and the CD4538 one shots. All inputs are protected from damage due to static discharge by diodes to  $V_{CC}$  and ground.

#### **Features**

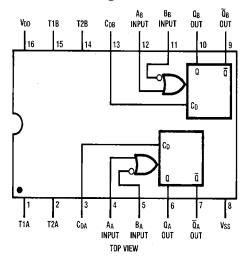
- Schmitt trigger on A and B inputs
- Wide power supply range: 2-6V
- Typical trigger propagation delay: 32 ns
- Fanout of 10 LS-TTL loads
- Low input current: 1 µA max

## **Ordering Code:**

Order Number	Package Number	Package Description
MM74HC4538M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
MM74HC4538SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4538N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

## **Connection Diagram**



#### **Truth Table**

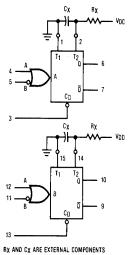
	Inputs	Outputs		
Clear	ear A		Q	Q
L	X	Χ	L	Н
Х	Н	Χ	L	Н
Х	Χ	L	L	Н
н	L	$\downarrow$	工	ᅚ
Н	<b>↑</b>	Н	7	75

- H = HIGH Level
- L = LOW Level
- ↑ = Transition from LOW-to-HIGH
- \_\_ = One HIGH Level Pulse \_\_ = One LOW Level Pulse
- X = Irrelevant

© 2000 Fairchild Semiconductor Corporation

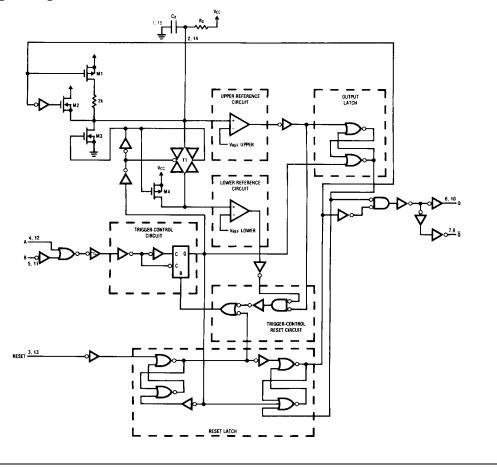
DS005217

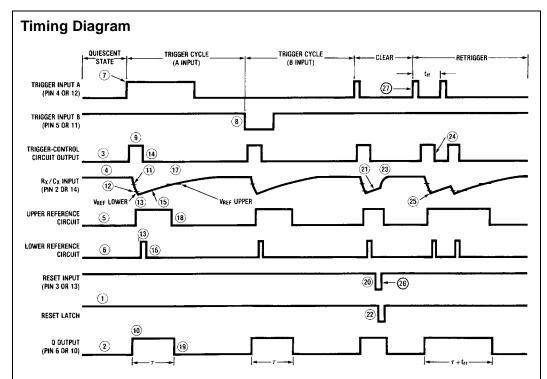
## **Block Diagrams**



Note: Pin 1 and Pin 15 must be hard-wired to GND.

## **Logic Diagram**





## **Circuit Operation**

The MM74HC4538 operates as follows (refer to logic diagram). In the quiescent state, the external timing capacitor,  $C_X$ , is charged to  $V_{CC}$ . When a trigger occurs, the Q output goes HIGH and  $C_X$  discharges quickly to the lower reference voltage ( $V_{REF}$  Lower =  $^1/_3$   $V_{CC}$ ).  $C_X$  then charges, through  $R_X$ , back up to the upper reference voltage ( $V_{REF}$  Upper =  $^2/_3$   $V_{CC}$ ), at which point the one-shot has timed out and the Q output goes LOW.

The following, more detailed description of the circuit operation refers to both the logic diagram and the timing diagram.

#### QUIESCENT STATE

In the quiescent state, before an input trigger appears, the output latch is HIGH and the reset latch is HIGH (#1 in logic diagram).

Thus the Q output (pin 6 or 10) of the monostable multivibrator is LOW (#2, timing diagram).

The output of the trigger-control circuit is LOW (#3), and transistors M1, M2, and M3 are turned off. The external timing capacitor,  $C_{\rm X}$ , is charged to  $V_{\rm CC}$  (#4), and the upper reference circuit has a LOW output (#5). Transistor M4 is turned ON and transmission gate T1 is turned OFF. Thus the lower reference circuit has  $V_{\rm CC}$  at the noninverting input and a resulting LOW output (#6).

In addition, the output of the trigger-control reset circuit is LOW.

#### TRIGGER OPERATION

The MM74HC4538 is triggered by either a rising-edge signal at input A (#7) or a falling-edge signal at input B (#8), with the unused trigger input and the Reset input held at the voltage levels shown in the Truth Table. Either trigger signal will cause the output of the trigger-control circuit to go HIGH (#9).

The trigger-control circuit going HIGH simultaneously initiates three events. First, the output latch goes LOW, thus taking the Q output of the HC4538 to a HIGH State (#10). Second, transistor M3 is turned on, which allows the external timing capacitor,  $C_{\rm X}$ , to rapidly discharge toward ground (#11). (Note that the voltage across  $C_{\rm X}$ appears at the input of the upper reference circuit comparator.) Third, transistor M4 is turned off and transmission gate T1 is turned ON, thus allowing the voltage across  $C_{\rm X}$  to also appear at the input of the lower reference circuit comparator

When  $C_X$  discharges to the reference voltage of the lower reference circuit (#12), the outputs of both reference circuits will be HIGH (#13). The trigger-control reset circuit goes HIGH, resetting the trigger-control circuit flip-flop to a LOW State (#14). This turns transistor M3 OFF again, allowing  $C_X$  to begin to charge back up toward  $V_{CC}$ , with a time constant  $t = R_X C_X$  (#15). In addition, transistor M4 is turned ON and transmission gate T1 is turned OFF. Thus a high voltage level is applied to the input of the lower reference circuit comparator, causing its output to go LOW (#16). The monostable multivibrator may be retriggered at any time after the trigger-control circuit goes LOW.

When  $C_X$  charges up to the reference voltage of the upper reference circuit (#17), the output of the upper reference circuit goes LOW (#18). This causes the output latch to

#### Circuit Operation (Continued)

toggle, taking the Q output of the HC4538 to a LOW State (#19), and completing the time-out cycle.

#### RESET OPERATION

A low voltage applied to the Reset pin always forces the Q output of the HC4538 to a LOW State.

The timing diagram illustrates the case in which reset occurs (#20) while  $C_{\rm X}$  is charging up toward the reference voltage of the upper reference circuit (#21). When a reset occurs, the output of the reset latch goes LOW (#22), turning ON transistor M1. Thus  $C_{\rm X}$  is allowed to quickly charge up to  $V_{\rm CC}$  (#23) to await the next trigger signal.

Recovery time is the required delay after reset goes inactive to a new trigger rising edge. On the diagram it is shown as (#26) to (#27).

#### **RETRIGGER OPERATION**

In the retriggerable mode, the HC4538 may be retriggered during timing out of the output pulse at any time after the trigger-control circuit flip-flop has been reset (#24). Because the trigger-control circuit flip-flop resets shortly after  $C_X$  has discharged to the reference voltage of the lower reference circuit (#25), the minimum retrigger time,  $t_{rr}$  is a function of internal propagation delays and the discharge time of  $C_X$ :

$$t_{rr}(ns) \approx 72 + \frac{V_{CC}(volts) \cdot C_X(pF)}{30.5}$$

at room temperature

#### POWER-DOWN CONSIDERATIONS

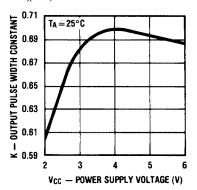
Large values of  $C_{\rm X}$  may cause problems when powering down the MM74HC4538 because of the amount of energy stored in the capacitor. When a system containing this

device is powered down, the capacitor may discharge from  $V_{CC}$  through the input protection diodes at pin 2 or pin 14. Current through the protection diodes must be limited to 30 mA; therefore, the turn-off time of the  $V_{CC}$  power supply must not be faster than t =  $V_{CC}{}^{\bullet}C_X/(30 \text{ mA})$ . For example, if  $V_{CC}$  = 5V and  $C_X$  = 15  $\mu F$ , the  $V_{CC}$  supply must turn OFF no faster than t = (15V) $^{\bullet}(15~\mu F)/30~mA$  = 2.5 ms. This is usually not a problem because power supplies are heavily filtered and cannot discharge at this rate.

When a more rapid decrease of V $_{CC}$  to zero volts occurs, the MM74HC4538 may sustain damage. To avoid this possibility, use an external clamping diode, D $_{X}$ , connected from V $_{CC}$  to the C $_{X}$  pin.

#### **SET UP RECOMMENDATIONS**

 $\label{eq:minimum} \begin{aligned} & \text{Minimum} & & R_X = 1 \text{ k}\Omega \\ & \text{Minimum} & & C_X = 0 \text{ pF.} \end{aligned}$ 



## Absolute Maximum Ratings(Note 1) (Note 2)

Power Dissipation ( $P_D$ )

(Note 3) 600 mW S.O. Package only 500 mW

Lead Temperature (T<sub>L</sub>)

(Soldering 10 seconds) 260°C

## Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V <sub>CC</sub> )	2	6	V
DC Input or Output Voltage	0	$V_{CC}$	V
(V <sub>IN</sub> , V <sub>OUT</sub> )			
Operating Temperature Range (T <sub>A</sub> )	-40	+85	°C
Input Rise or Fall Times			
(Reset only)			
$(t_{r}, t_{f}) V_{CC} = 2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns

Note 1: Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation Temperature Derating: Plastic "N" Package: –
12mW/°C from 65°C to 85°C.

### DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	Voc	V <sub>CC</sub> T <sub>A</sub> = 25°	25°C	$T_A = -40 \text{ to } 85^{\circ}\text{C}$	T <sub>A</sub> = -55 to 125°C	Units
Зуппоот	Farameter	Conditions	• 66	Тур	Guara	anteed Limits		Units
V <sub>IH</sub>	Minimum HIGH Level Input		2.0V		1.5	1.5	1.5	V
	Voltage		4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V <sub>IL</sub>	Maximum LOW Level Input		2.0V		0.5	0.5	0.5	V
	Voltage		4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V <sub>OH</sub>	Minimum HIGH Level Output	$V_{IN} = V_{IH}$ or $V_{IL}$						
VIL N VOH N V VOL N VIIN N (I IIN N (I IIN C ICC N Active C Quiescent C	Voltage	$ I_{OUT}  \le 20 \mu A$	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		$V_{IN} = V_{IH}$ or $V_{IL}$						
		$ I_{OUT}  \le 4.0 \text{ mA}$	4.5V		3.98	3.84	3.7	V
		I <sub>OUT</sub>   ≤ 5.2 mA	6.0V		5.48	5.34	5.2	V
V <sub>OL</sub>	Maximum LOW Level Output	$V_{IN} = V_{IH}$ or $V_{IL}$	2.0V	0	0.1	0.1	0.1	V
	Voltage	$ I_{OUT}  \le 20 \mu A$	4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		$V_{IN} = V_{IH}$ or $V_{IL}$						
		$ I_{OUT}  \le 4.0 \text{ mA}$	4.5V		0.26	0.33	0.4	V
		$ I_{OUT}  \le 5.2 \text{ mA}$	6.0V		0.26	0.33	0.4	V
I <sub>IN</sub>	Maximum Input Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	6.0V		±0.1	±1.0	±1.0	μА
	(Pins 2, 14) (Note 5)							
I <sub>IN</sub>	Maximum Input Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	6.0V		±0.1	±1.0	±1.0	μА
	(all other pins)							
I <sub>CC</sub>	Maximum Active Supply	Pins 2, 14 = 0.5 V <sub>CC</sub>						
Active	Current	Q1, Q2 = HIGH	6.0V		150	250	400	μΑ
		$V_{IN} = V_{CC}$ or GND						
I <sub>CC</sub>	Maximum Quiescent Supply	Pins 2, 14 = OPEN						
Quiescent	Current	Q1, Q2 = LOW	6.0V		130	220	350	μΑ
IN CC Active		$V_{IN} = V_{CC}$ or GND						

Note 4: For a power supply of 5V  $\pm$ 10% the worst case output voltages (V<sub>OH</sub>, and V<sub>OL</sub>) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V<sub>IH</sub> and V<sub>IL</sub> occur at V<sub>CC</sub> = 5.5V and 4.5V respectively. (The V<sub>IH</sub> value at 5.5V is 3.85V.) The worst case leakage current (I<sub>IN</sub>, I<sub>CC</sub>, and I<sub>OZ</sub>) occur for CMOS at the higher voltage and so the 6.0V values should be used.

## DC Electrical Characteristics (Continued) Note 5: The device must be set up with 3 steps before measuring $I_{\text{IN}}$ :

	Clear	Α	В	
1.	Н	L	Н	
2.	Н	Н	Н	
3.	Н	L	Н	

## **AC Electrical Characteristics**

 $V_{CC} = 5V$ ,  $T_A = 25^{\circ}$  C,  $C_L = 15$  pF,  $t_r = t_f = 6$  ns

Symbol	Parameter	Conditions	Тур	Limit	Units
t <sub>PLH</sub>	Maximum Propagation Delay A, or B to Q		23	45	ns
t <sub>PHL</sub>	Maximum Propagation Delay A, or B to $\overline{\mathbb{Q}}$		26	50	ns
t <sub>PHL</sub>	Maximum Propagation Delay Clear to Q		23	45	ns
t <sub>PLH</sub>	Maximum Propagation Delay Clear to Q		26	50	ns
t <sub>W</sub>	Minimum Pulse Width A, B or Clear		10	16	ns

#### **AC Electrical Characteristics**

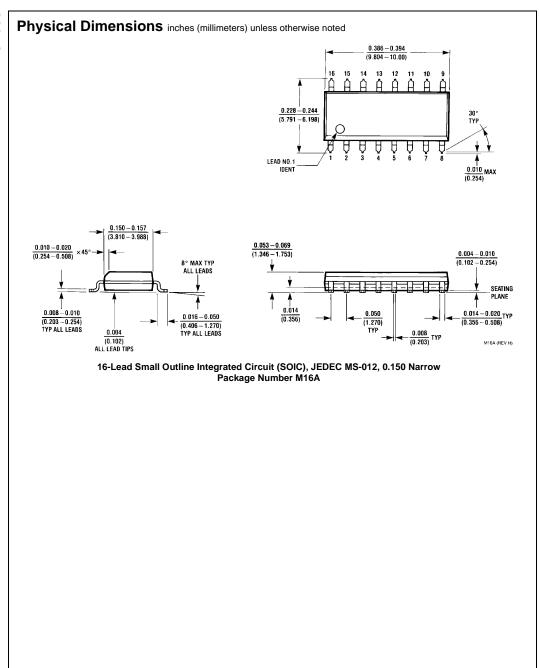
 $C_L = 50\ pF,\ t_f = t_f = 6\ \text{ns}$  (unless otherwise specified)

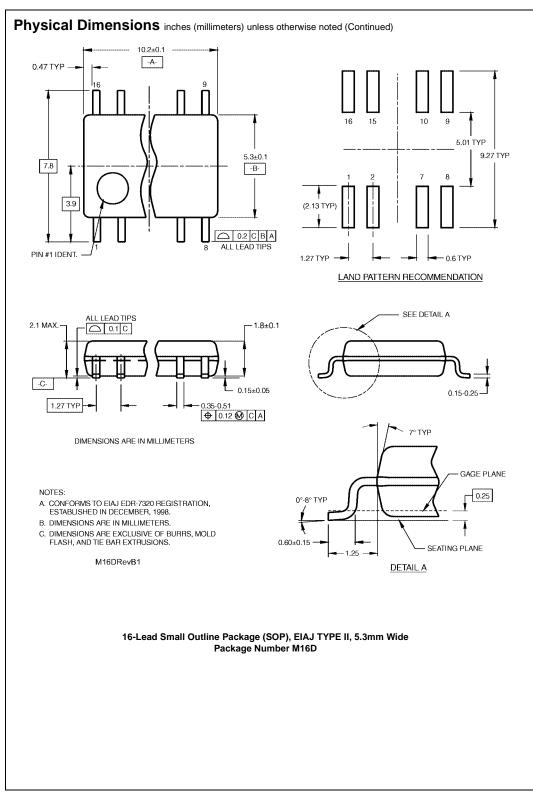
Symbol	Parameter	Conditi	one	V <sub>CC</sub>	T <sub>A</sub> =25°C T <sub>A</sub> =-40 to 85°C		T <sub>A</sub> = -55 to 125°C	Units	
	raiailletei	Conditi	Conditions		Тур	Guar	anteed Limits		Units
t <sub>PLH</sub>	Maximum Propagation			2.0V	100	250	315	373	ns
	Delay A, or B to Q			4.5V	25	50	63	75	ns
				6.0V	21	43	54	63	ns
t <sub>PHL</sub>	Maximum Propagation			2.0V	110	275	347	410	ns
	Delay A, or B to Q			4.5V	28	55	69	82	ns
				6.0V	23	47	59	70	ns
t <sub>PHL</sub>	Maximum Propagation			2.0V	100	250	315	373	ns
	Delay Clear to Q			4.5V	25	50	63	75	ns
				6.0V	21	43	54	63	ns ns ns ns ns
t <sub>PLH</sub>	Maximum Propagation			2.0V	110	275	347	410	ns
	Delay Clear to Q			4.5V	28	55	69	82	ns
				6.0V	23	47	59	70	ns
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output			2.0V	30	75	95	110	ns
	Rise and Fall			4.5V	10	15	19	22	ns
	Time			6.0V	8	13	16	19	ns
t <sub>r</sub> , t <sub>f</sub>	Maximum Input			2.0V		1000	1000	1000	ns
	Rise and Fall			4.5V		500	500	500	ns
	Time (Reset only)			6.0V		400	400	400	ns
t <sub>W</sub>	Minimum Pulse Width			2.0V		80	101	119	ns
	A, B, Clear			4.5V		16	20	24	ns
				6.0V		14	17	20	ns
t <sub>REC</sub>	Minimum Recovery			2.0V	-5	0	0	0	ns n
	Time, Clear			4.5V		0	0	0	
	Inactive to A or B			6.0V		0	0	0	ns
t <sub>WQ</sub>	Output Pulse Width	C <sub>X</sub> = 12 pF	Min	3.0V	283	190			ns
		$R_X = 1 k\Omega$		5.0V	147	120			ns
			Max	3.0V	283	400			ns
				5.0V	147	185			ns
t <sub>WQ</sub>	Output Pulse Width	C <sub>X</sub> = 100 pF	Min	3.0V	1.2				μs
		$R_X = 10 \text{ k}\Omega$		5.0V	1.0				μs
			Max	3.0V	1.2				μs
				5.0V	1.0				μs

## AC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions		V <sub>CC</sub>	T <sub>A</sub> =25°C		T <sub>A</sub> =-40 to 85°C	$T_A = -55$ to 125°C	Units	
Cy20.	. a.a.noto.	00.14.11		00	Тур	Guar	Guaranteed Limits		•	
t <sub>WQ</sub>	Output Pulse Width	C <sub>X</sub> = 1000 pF	Min	3.0V	10.5	9.4			μs	
		$R_X = 10 \text{ k}\Omega$		5.0V	10.0	9.3			μs	
			Max	3.0V	10.5	11.6			μs	
				5.0V	10.0	10.7			μs	
t <sub>WQ</sub>	Output Pulse Width	$C_X = 0.1 \mu F$	Min	5.0V		0.63	0.602	0.595	ms	
		$R_X = 10k$	Max	5.0V		0.77	0.798	0.805	ms	
C <sub>IN</sub>	Maximum Input				25				pF	
	Capacitance (Pins 2 & 14)									
C <sub>IN</sub>	Maximum Input				5	10	10	10	pF	
	Capacitance (other inputs)									
C <sub>PD</sub>	Power Dissipation	(per one s	shot)		150				pF	
	Capacitance (Note 6)									
$\Delta t_{WQ}$	Pulse Width Match									
	Between Circuits in				±1				%	
	Same Package									

Note 6:  $C_{PD}$  determines the no load dynamic consumption,  $P_D = C_{PD} \ V_{CC}^2 f + I_{CC} \ V_{CC}$ , and the no load dynamic current consumption,  $I_S = V_{CC} \ f + I_{CC} \ V_{CC}$ 





#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued) 0.740 - 0.780 0.090 (18.80 - 19.81)(2.286)<u>16 15 14 13 12 11 10 9</u> 16 15 INDEX AREA 0.250 ± 0.010 $\overline{(6.350 \pm 0.254)}$ PIN NO. 1 PIN NO. 1 1 2 3 4 5 6 7 8 1 2 OPTION 01 OPTION 02 0.065 $\frac{0.130 \pm 0.005}{(3.302 \pm 0.127)}$ $\frac{0.060}{(1.524)}$ TYP (1.651)4° TYP 0.300 - 0.320OPTIONAL (7.620 - 8.128) 0.145 - 0.200 (3.683 - 5.080)95°±5° 0.008 = 0.016 (0.203 = 0.406) TYP 90°±4° 0.020 $\frac{0.280}{(7.112)}$ MIN (0.508)0.125 - 0.150 (3.175 - 3.810) 0.030 ± 0.015 $(0.762 \pm 0.381)$ 0.014 - 0.023 0.100 ± 0.010 (0.325 +0.040 -0.015 (0.356 - 0.584) $(2.540 \pm 0.254)$ 0.050 ± 0.010 N16E (REV F) TYP (1.270 ± 0.254)

16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide Package Number N16E

Fairchild does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and Fairchild reserves the right at any time without notice to change said circuitry and specifications.

### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com

ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hol

Phone: 81-3-5817-1050

#### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative